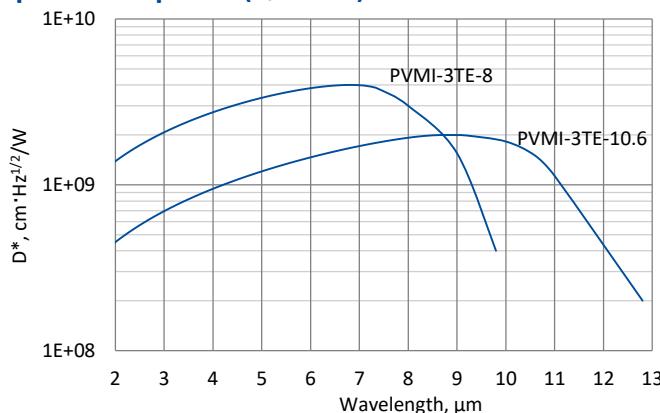


## PVMI-3TE series

### 2.0 – 13.0 $\mu\text{m}$ HgCdTe three-stage thermoelectrically cooled, optically immersed photovoltaic multiple junction detectors

**PVMI-3TE series** features three-stage thermoelectrically cooled IR photovoltaic multiple junction detectors based on sophisticated HgCdTe heterostructures for the best performance and stability, optically immersed in order to improve parameters of the devices. The detectors are optimized for the maximum performance at  $\lambda_{\text{opt}}$ . They are especially useful as large optical area detectors operating within 2.0 to 13.0  $\mu\text{m}$  spectral range. 3° wedged zinc selenide anti-reflection coated (wZnSeAR) window prevents unwanted interference effects.

#### Spectral response ( $T_a = 20^\circ\text{C}$ )



Exemplary spectral detectivity, the spectral response of delivered devices may differ.

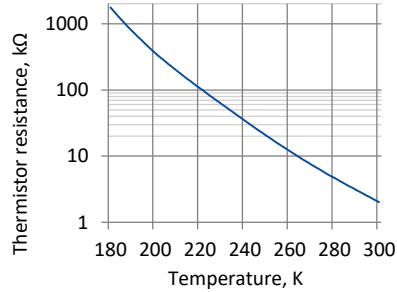
#### Specification ( $T_a = 20^\circ\text{C}$ )

Parameter	Detector type	
	PVMI-3TE-8	PVMI-3TE-10.6
Active element material	epitaxial HgCdTe heterostructure	
Optimal wavelength $\lambda_{\text{opt}}$ , $\mu\text{m}$	8.0	10.6
Detectivity $D^*(\lambda_{\text{peak}})$ , $\text{cm} \cdot \text{Hz}^{1/2} / \text{W}$	$\geq 4.0 \times 10^9$	$\geq 2.0 \times 10^9$
Detectivity $D^*(\lambda_{\text{opt}})$ , $\text{cm} \cdot \text{Hz}^{1/2} / \text{W}$	$\geq 3.0 \times 10^9$	$\geq 1.5 \times 10^9$
Current responsivity $R_i(\lambda_{\text{opt}})$ , $\text{A/W}$	$\geq 0.15$	$\geq 0.10$
Time constant $\tau$ , ns	$\leq 4$	$\leq 3$
Resistance $R$ , $\Omega$	200 to 1500	100 to 400
Active element temperature $T_{\text{det}}$ , K	$\sim 210$	
Optical area $A_o$ , mm × mm	1 × 1	
Package	TO8, TO66	
Acceptance angle $\Phi$	$\sim 36^\circ$	
Window	wZnSeAR	

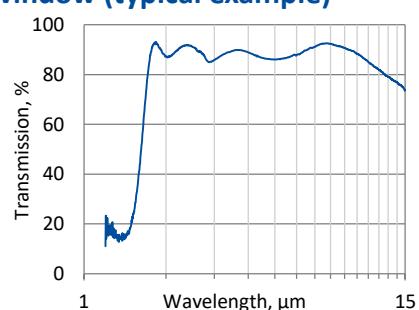
#### Three-stage thermoelectric cooler parameters

Parameter	Value
$T_{\text{det}}$ , K	$\sim 210$
$V_{\text{max}}$ , V	3.6
$I_{\text{max}}$ , A	0.45
$Q_{\text{max}}$ , W	0.27

#### Thermistor characteristics

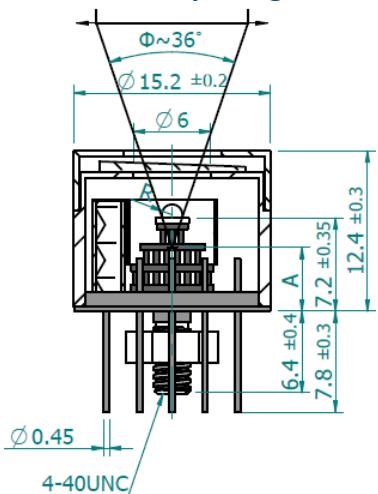


#### Spectral transmission of wZnSeAR window (typical example)



## Mechanical layout, mm

## 3TE-T08 package



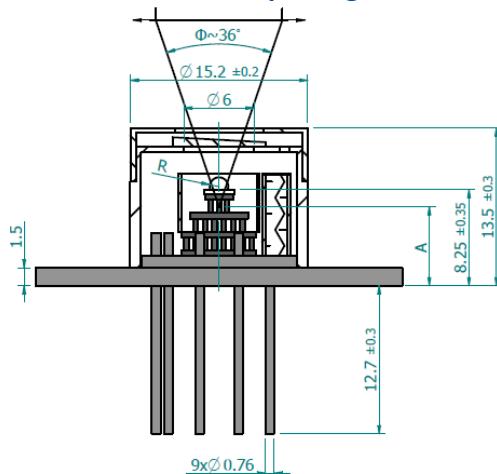
Parameter	Value
Immersion microlens shape	hyperhemisphere
Optical area $A_0$ , mm $\times$ mm	1 $\times$ 1
$R$ , mm	0.8
$A$ , mm	4.8 $\pm$ 0.35

$\Phi$  – acceptance angle

R – hyperhemisphere microlens radius

A – distance from the bottom of 3TE-T08 header to the focal plane

## 3TE-TO66 package



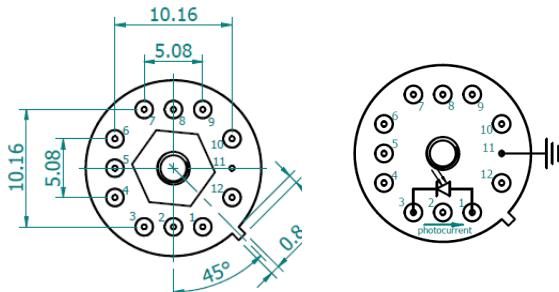
Parameter	Value
Immersion microlens shape	hyperhemisphere
Optical area $A_0$ , mm $\times$ mm	1 $\times$ 1
R, mm	0.8
A, mm	5.85 $\pm$ 0.35

$\Phi$ - acceptance angle

R – hyperhemisphere microlens radius

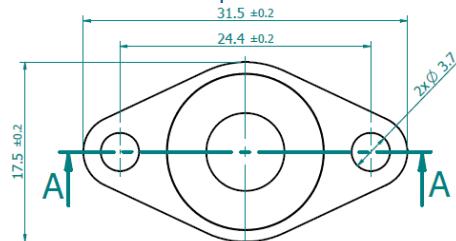
A – distance from the bottom of 3TE-T066 header to the focal plane

## Bottom view

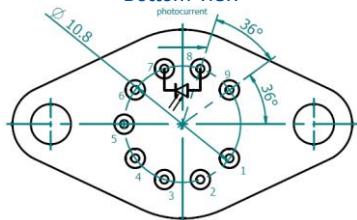


Function	Pin number
Detector	1, 3
Thermistor	7, 9
TE cooler supply	2(+), 8(-)
Chassis ground	11
Not used	4, 5, 6, 10, 12

## Top view



## Bottom view



Function	Pin number
Detector	7, 8
Thermistor	5, 6
TE cooler supply	1(+), 9(−)
Not used	2, 3, 4

## Dedicated preamplifiers



## „all-in-one“ AIP



programmable PIP



### standard MIP



small SIP-T08